

L Number	Hits	Search Text	DB	Time stamp
30	855	high adj voltage adj semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/01/08 14:34
31	18	(high adj voltage adj semiconductor) same (edg\$3 adj (structure or device))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/01/08 14:37
32	97	(257/168).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/01/08 14:37
33	708	(257/409).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/01/08 14:37